Product Specification

PE4246

Absorptive SPST UltraCMOS™ RF Switch: 1 - 5000 MHz

Features

- Non-reflective 50-ohm RF switch
- 50-ohm (0.25 watt) terminations
- High isolation: 55 dB at 1000 MHz, 48 dB at 3000 MHz
- Low insertion loss: 0.8 dB at 1000 MHz, 0.9 dB at 3000 MHz
- High linearity: +33 dBm input 1dB compression point
- CMOS/TTL single-pin control
- Single +3-volt supply operation
- Extremely low bias: 33 µA @ 3 V
- Available in a 6-lead DFN package

Product Description

The PE4246 RF Switch is designed to cover a broad range of applications from 1 to 5000 MHz. It is non-reflective at both RF1 and RF2 ports. This SPST switch integrates a single-pin CMOS control interface, and provides low insertion loss while operating with extremely low bias from a single +3-volt supply. In a typical application, the high isolation PE4246 can replace multiple RF switches of lesser isolation performance. It is offered in a small 3x3 mm DFN package.

The PE4246 is manufactured on Peregrine's UltraCMOS™ process, a patented variation of silicon-on-insulator (SOI) technology on a sapphire substrate, offering the performance of GaAs with the economy and integration of conventional CMOS.

Figure 1. Functional Diagram

Peregrine Specification 71/0008

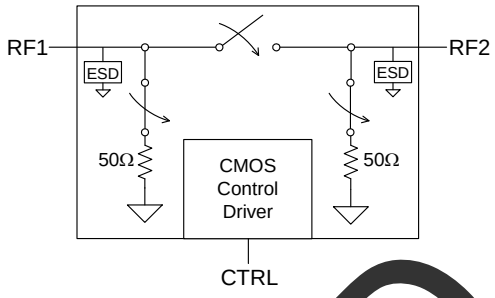


Figure 2. Package Type

6-lead DFN



Table 1. Electrical Specifications @ +25 °C, V_{DD} = 3 V (ZS = ZL = 50 Ω)

Parameter	Condition	Minimum	Typical	Maximum	Units
Operation Frequency[1]		1		5000	MHz
Operating Power	CTRL=1/CTRL=0			30/24	dBm
Insertion Loss	1-2000 MHz 2000-3000 MHz 3000-4000 MHz 4000-5000 MHz		0.8 0.9 1.0 1.3	1.0 1.1 1.3 1.8	dB dB dB dB
Isolation	1-2000 MHz 2000-3000 MHz 3000-4000 MHz 4000-5000 MHz	49 45 43 40	55 48 46 44		dB dB dB dB
Return Loss	1-5000 MHz	11	20		dB
Input 1 dB Compression[3]	1-5000 MHz	30	33		dBm
Input IP3	1-5000 MHz	50			dBm
Video Feedthrough[2]				15	mV_{pp}
Switching Time			2		µs

Notes: 1. Device linearity will begin to degrade below 1 MHz.

2. The DC transient at the output of the switch when the control voltage is switched from Low to High or High to Low in a 50 Ω test set-up, measured with 1ns risetime pulses and 500 MHz bandwidth.
3. Note Absolute Maximum ratings in Table 3.

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Figure 3. Pin Configuration

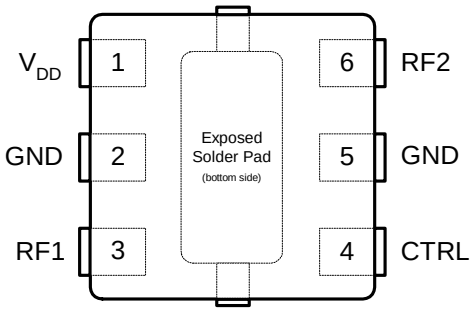


Table 2. Pin Descriptions

Pin No.	Pin Name	Description
1	V_{DD}	Nominal 3 V supply connection.[1]
2	GND	Ground connection. [3]
3	RF1	RF port. [2]
4	CTRL	CMOS or TTL logic level: High = RF1 to RF2 signal path Low = RF1 isolated from RF2
5	GND	Ground connection. [3]
6	RF2	RF port. [2]

Notes: 1. A bypass capacitor should be placed as close as possible to the pin.
2. Both RF pins must be DC blocked by an external capacitor or held at 0 V_{DC}.
3. The exposed pad must be soldered to the ground plane for proper switch performance.

Table 3. Absolute Maximum Ratings

Symbol	Parameter/Condition	Min	Max	Unit
V_{DD}	Power supply voltage	-0.3	4.0	V
V_I	Voltage on CTRL input	-0.3	5.5	V
T_{ST}	Storage temperature	-65	150	°C
P_{IN}	Input power (50 Ω), CTRL=1/CTRL=0		33/24	dBm
V_{ESD}	ESD voltage (Human Body Model)		200	V

Exceeding absolute maximum ratings may cause permanent damage. Operation should be restricted to the limits in the Operating Ranges table. Operation between operating range maximum and absolute maximum for extended periods may reduce reliability.

Moisture Sensitivity Level

The Moisture Sensitivity Level rating for the PE4246 in the 6-lead 3x3 DFN package is MSL1.

Device Description

The PE4246 high-isolation SPST RF Switch is designed to support a variety of applications where high isolation performance is demanded and a non-reflective input and output is desired. This switch is able to replace multiple lesser performing switches in a very small 3x3 mm DFN footprint.

Table 4. Operating Ranges

Parameter	Min	Typ	Max	Unit
V_{DD} Power Supply	2.7	3.0	3.3	V
I_{DD} Power Supply Current (V_{DD} = 3 V, V_{CNTL} = 3 V)		33	40	µA
T_{OP} Operating temperature	-40		85	°C
Control Voltage High	0.7xV_{DD}		5	V
Control Voltage Low	0		0.3xV_{DD}	V

Table 5. Control Logic Truth Table

Control Voltage	Signal Path
CTRL = CMOS or TTL High	RF1 to RF2
CTRL = CMOS or TTL Low	RF1 isolated from RF2

Control Logic

The control logic input pin (CTRL) is typically driven by a 3-volt CMOS logic level signal, and has a threshold of 50% of V_{DD}. For flexibility to support systems that have 5-volt control logic drivers, the control logic input has been designed to handle a 5-volt logic HIGH signal. (A minimal current will be sourced out of the V_{DD} pin when the control logic input voltage level exceeds V_{DD}.)

Electrostatic Discharge (ESD) Precautions

When handling this UltraCMOS™ device, observe the same precautions that you would use with other ESD-sensitive devices. Although this device contains circuitry to protect it from damage due to ESD, precautions should be taken to avoid exceeding the rating specified in Table 3.

Latch-Up Avoidance

Unlike conventional CMOS devices, UltraCMOS™ devices are immune to latch-up.

NOT RECOMMENDED FOR NEW DESIGN

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Typical Performance Data @ 25 °C (Unless Otherwise Noted)

Figure 4. Insertion Loss
T = -40 °C to 85 °C

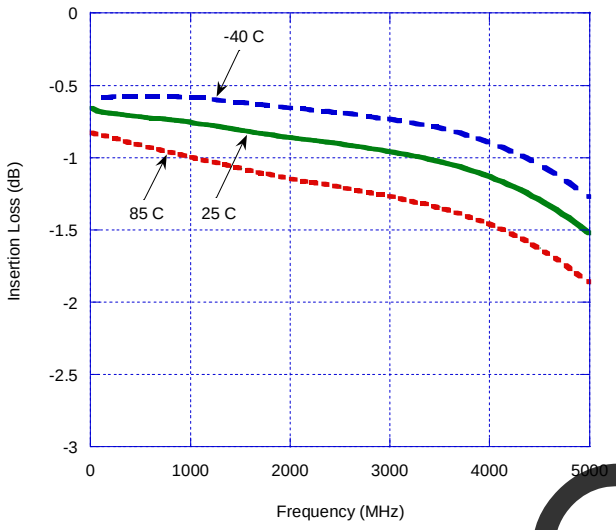


Figure 5. Input 1dB Compression Point and IIP3

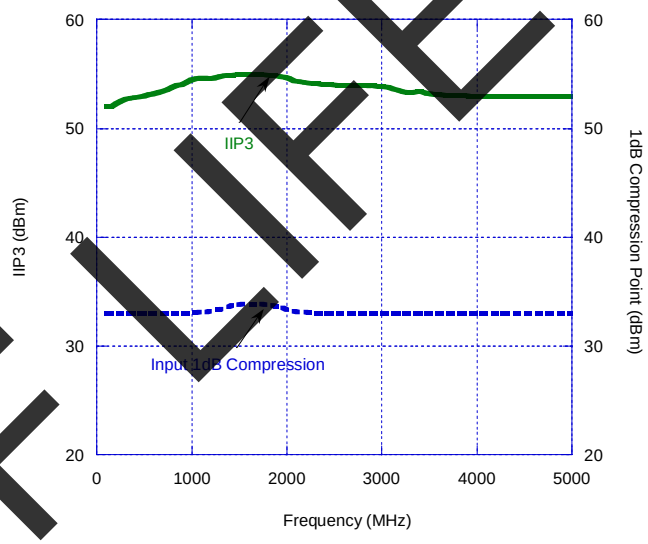
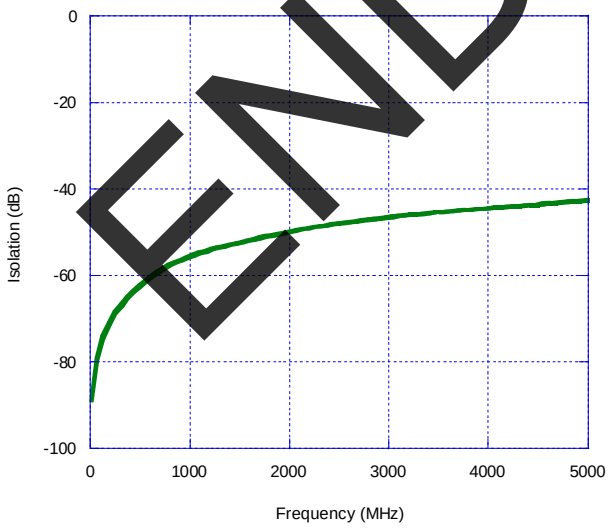


Figure 6. Isolation



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Typical Performance Data @ +25 °C

Figure 7. RF1 Return Loss (CTRL = High)

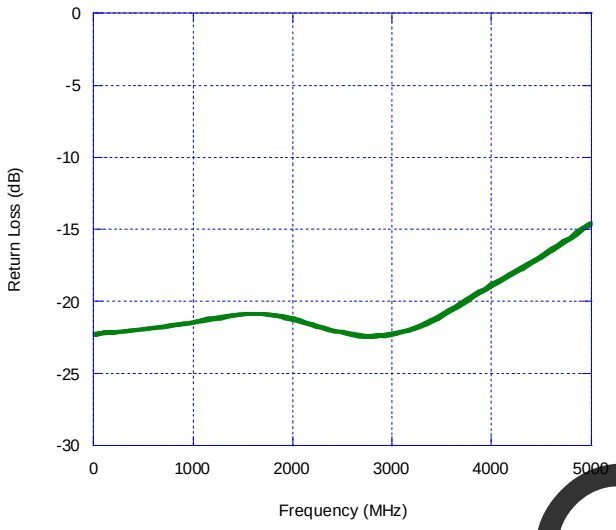
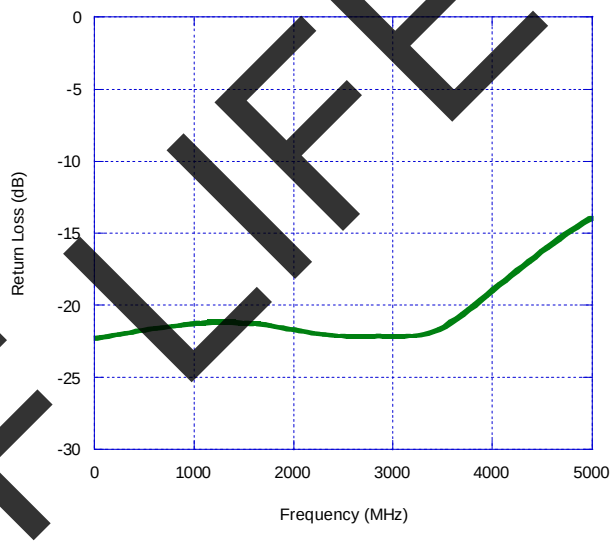


Figure 8. RF2 Return Loss (CTRL = High)



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Figure 9. RF1 Return Loss (CTRL = Low)

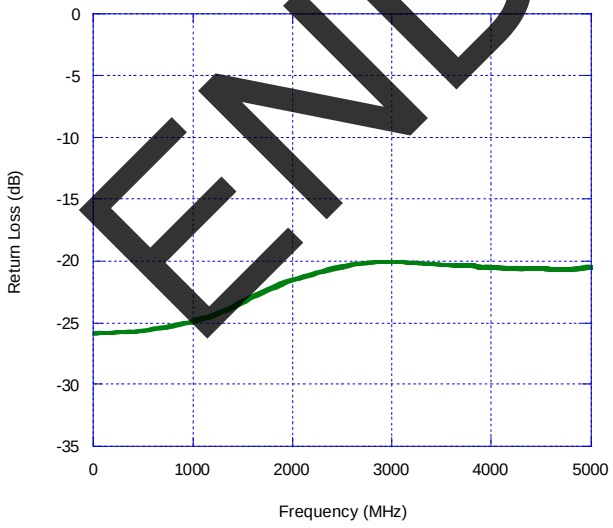
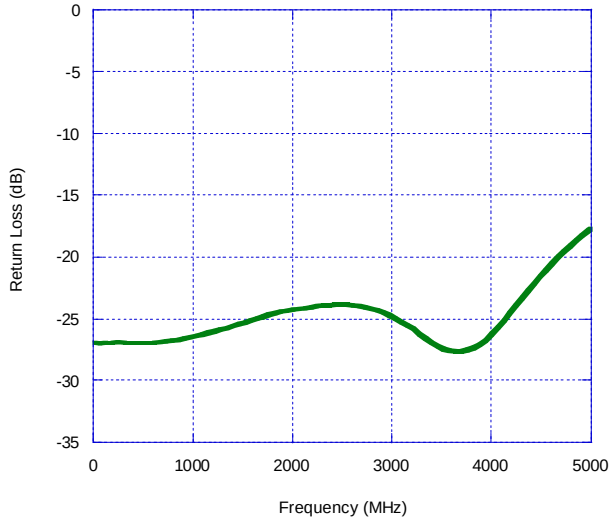


Figure 10. RF2 Return Loss (CTRL = Low)



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Evaluation Kit

The SPST Switch Evaluation Kit board was designed to ease customer evaluation of the PE4246 SPST switch. The RF1 port is connected through a 50 Ω transmission line to the top left SMA connector, J1. The RF2 port is connected through a 50 Ω transmission line to the top right SMA connector, J2. A through transmission line connects SMA connectors J3 and J4. This transmission line can be used to estimate the loss of the PCB over the environmental conditions being evaluated.

The board is constructed of a two metal layer FR4 material with a total thickness of 0.031". The bottom layer provides ground for the RF transmission lines. The transmission lines were designed using a coplanar waveguide model with trace width of 0.0476", trace gaps of 0.030", dielectric thickness of 0.028", metal thickness of 0.0021" and εR of 4.3. Note that the predominate mode for these transmission lines is coplanar waveguide with a ground plane.

J5 and J6 provide a means for controlling DC and digital inputs to the device. J6-1 is connected to the device V_{DD} input. J5-1 is connected to the device CTRL input. J5-2 and J6-2 are GND connections. A decoupling capacitor (100 pF) is provided on both CTRL and V_{DD} traces. It is the responsibility of the customer to determine proper supply decoupling for their design application. Removing these components from the evaluation board has not been shown to degrade RF performance.

Figure 11. Evaluation Board Layouts
Peregrine Specification 101/0102

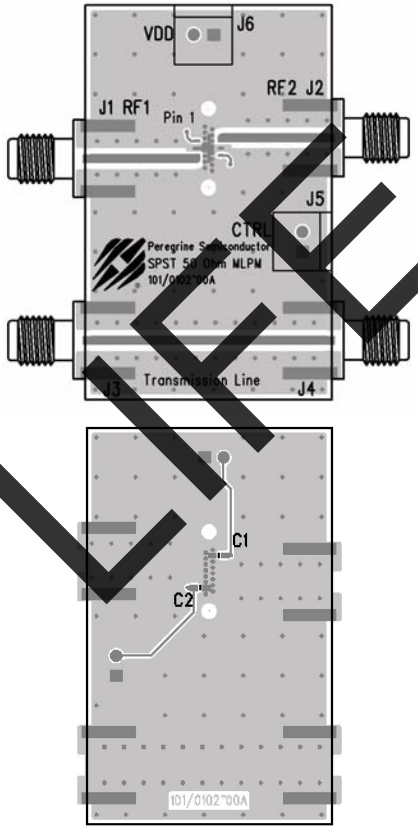
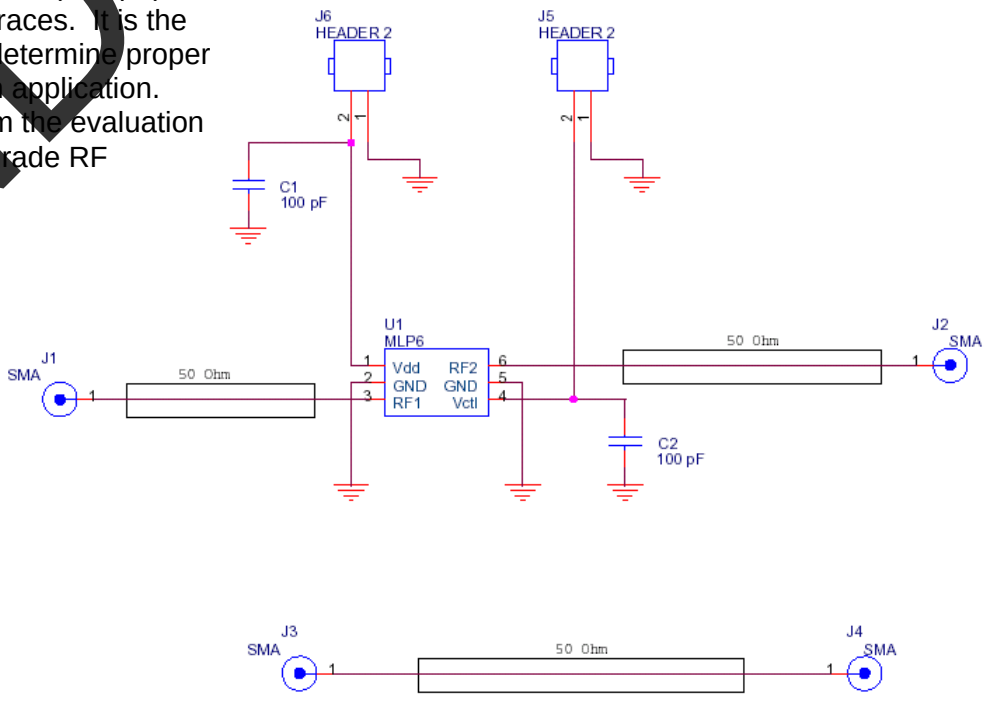


Figure 12. Evaluation Board Schematic
Peregrine Specification 102/0134



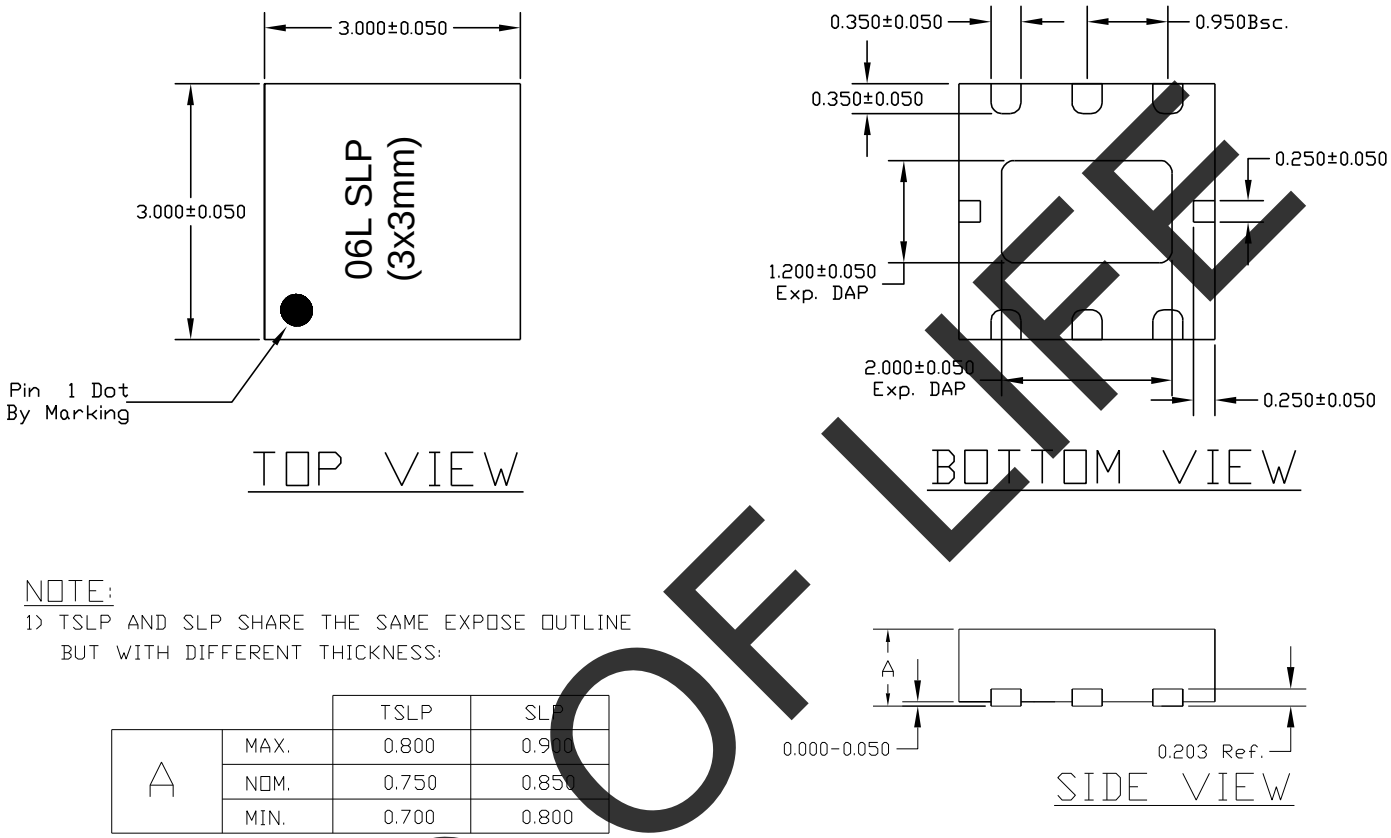
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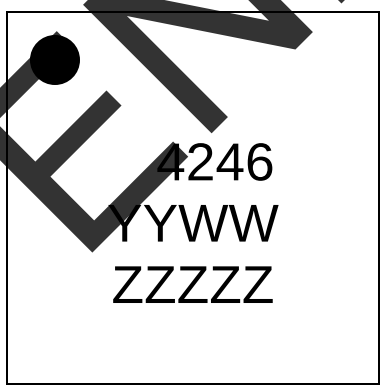
Figure 13. Package Drawing

6-lead DFN



NOTE: The exposed solder pad (on the bottom of the package) is not electrically connected to any other pin (isolated).

Figure 14. Marking Specifications



YYWW = Date Code (last two digits of year and work week)
ZZZZZ = Last five digits of Lot Number

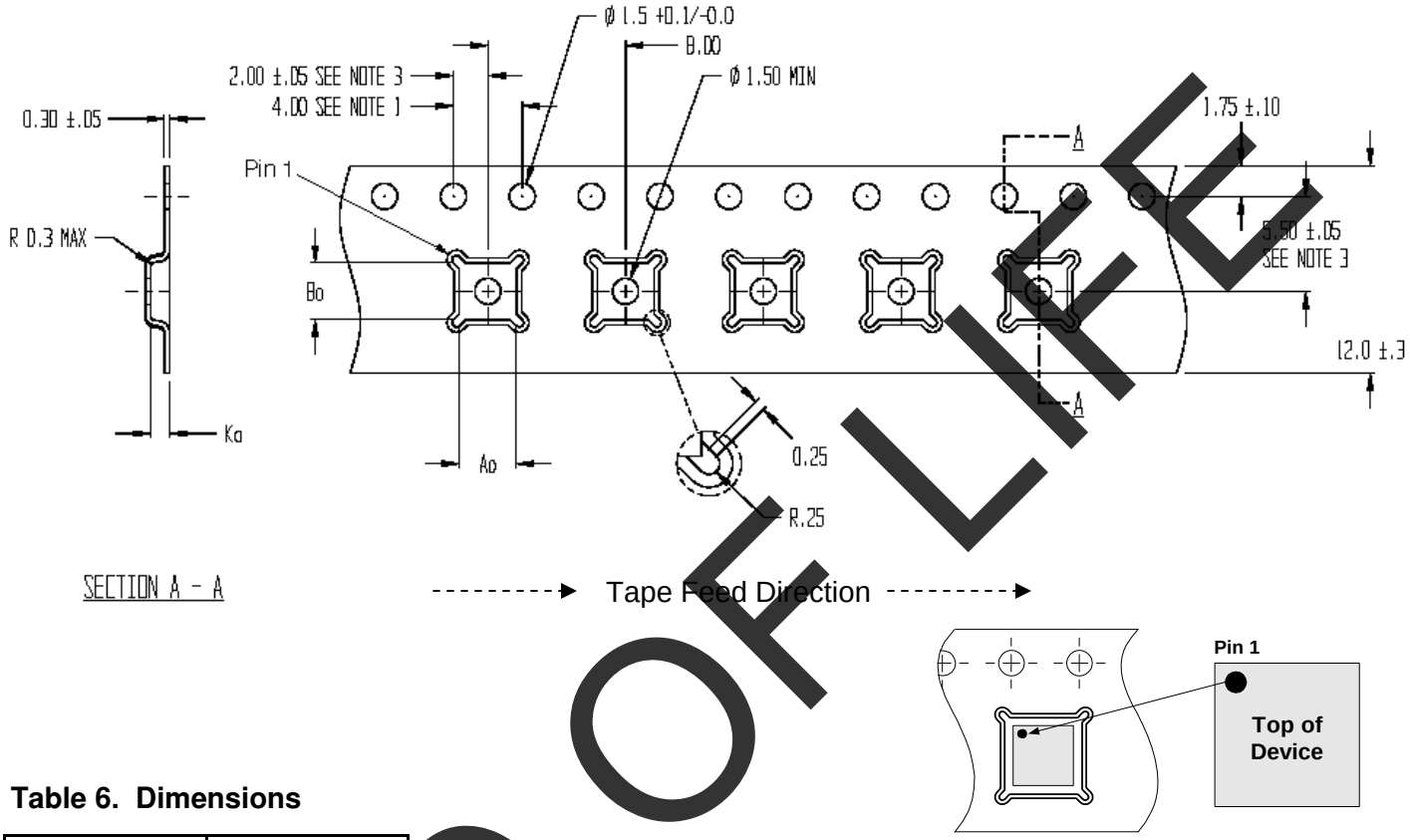
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Figure 15. Tape and Reel Specifications

6-lead DFN



Device Orientation in Tape

NOTES:
1. 10 SPROCKET HOLE PITCH CUMULATIVE TOLERANCE ±0.2
2. CAMBER IN COMPLIANCE WITH EIA 481
3. POCKET POSITION RELATIVE TO SPROCKET HOLE MEASURED AS TRUE POSITION OF POCKET, NOT POCKET HOLE

Table 6. Dimensions

Dimension	DFN 3x3 mm
Ao	3.23 ± 0.1
Bo	3.17 ± 0.1
Ko	1.37 ± 0.1
P	4 ± 0.1
W	8 +0.3, -0.1
T	0.254 ± 0.02
R7 Quantity	3000
R13 Quantity	N.A.

Note: R7 = 7 inch Lock Reel, R13 = 13 inch Lock Reel

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Table 7. Ordering Information

Order Code	Part Marking	Description	Package	Shipping Method
4246-51	4246	PE4246G-06DFN 3x3mm-12800F	Green 6-lead 3x3 mm DFN	Tape or loose
4246-52	4246	PE4246G-06DFN 3x3mm-3000C	Green 6-lead 3x3 mm DFN	3000 units / T&R
4246-00	PE4246-EK	PE4246-06DFN 3x3mm-EK	Evaluation Kit	1 / Box

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Data Sheet Identification

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